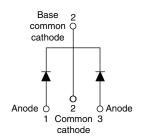


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## Schottky Rectifier, 2 x 10 A



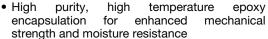


TO-220AB
I O-ZZUAD

PRODUCT SUMMARY						
Package	TO-220AB					
I <sub>F(AV)</sub>	2 x 10 A					
$V_{R}$	35 V, 45 V					
V <sub>F</sub> at I <sub>F</sub>	0.57 V					
I <sub>RM</sub> max.	15 mA at 125 °C					
T <sub>J</sub> max.	150 °C					
Diode variation	Common cathode					
E <sub>AS</sub>	8 mJ					

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

#### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform (per device)	20	А			
V <sub>RRM</sub>		35/45	V			
I <sub>FRM</sub>	T <sub>C</sub> = 135 °C (per leg)	20	Δ.			
I <sub>FSM</sub>	t <sub>p</sub> = 5 µs sine	1060	A			
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V			
TJ	Range	- 65 to 150	°C			

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBR2035CTPbF	VS-MBR2035CT-N3	VS-MBR2045CTPbF	VS-MBR2045CT-N3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	35	35	45	45	V		
Maximum working peak reverse voltage	$V_{RWM}$	33	33	45	43	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST (	CONDITIONS	VALUES	UNITS	
Maximum average per leg	I	T 135 °C rated V-		10		
forward current per device	IF(AV)	$I_{F(AV)}$ $T_C = 135 ^{\circ}\text{C}$ , rated $V_R$		20		
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 135 °C		20		
Non-repetitive peak surge current	I <sub>ESM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1060	Α	
	1 GW	Surge applied at rated load single phase, 60 Hz	condition half wave,	150		
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by $T_J$ maximum $V_A=1.5~x~V_R$ typical		2		
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 4 mH		8	mJ	

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		20 A	T <sub>J</sub> = 25 °C	0.84		
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	T _ 105 °C	0.57	V	
		20 A	- T <sub>J</sub> = 125 °C	0.72		
Mariana	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.1	- mA	
Maximum instantaneous reverse current		T <sub>J</sub> = 125 °C		15		
Threshold voltage	V <sub>F(TO)</sub>	$T_{.1} = T_{.1}$ maximum		0.354	V	
Forward slope resistance	r <sub>t</sub>	ıj = ıjınaxımum		17.6	mΩ	
Maximum junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		600	pF	
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

#### Note

<sup>(1)</sup> Pulse width  $< 300 \mu s$ , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS			
Maximum junction temperature range	$T_{J}$		- 65 to 150	°C			
Maximum storage temperature range	T <sub>Stg</sub>		- 65 to 175	C			
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	2.0	°C/W			
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased (only for TO-220)	0.50	C/VV			
Approximate weight			2	g			
Approximate weight			0.07	OZ.			
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf · cm			
maximum		Non-lubricated timeads	12 (10)	(lbf · in)			
Marking daying		Case style TO-220AB	MBR20	035CT			
Marking device		Case style 10-220AD	MBR2045CT				

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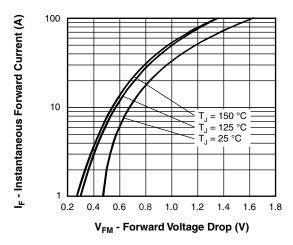


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

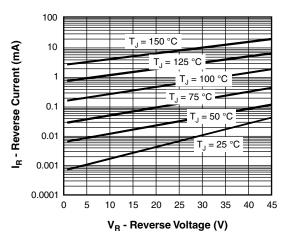


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

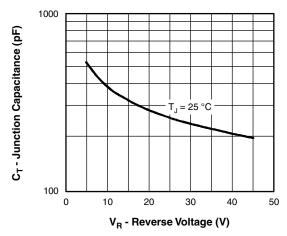


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

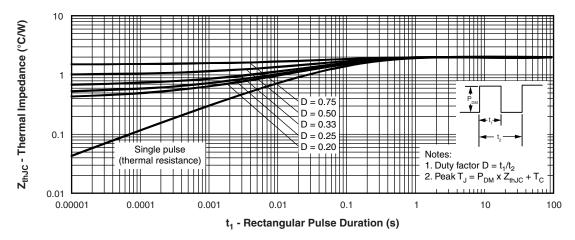


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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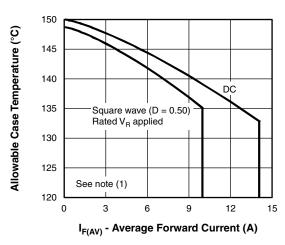


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

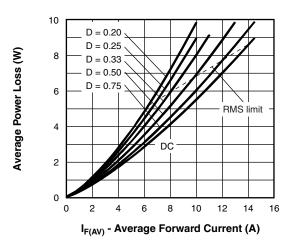


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

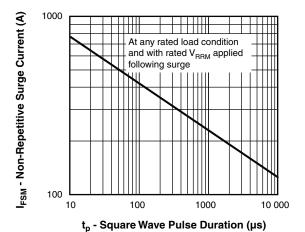


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

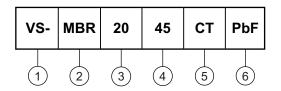
#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 

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#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Schottky MBR series

3 - Current rating (20 = 20 A)

35 = 35 V 45 = 45 V

- CT = Essential part number

6 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-MBR2035CTPbF	50	1000	Antistatic plastic tube				
VS-MBR2035CT-N3	50	1000	Antistatic plastic tube				
VS-MBR2045CTPbF	50	1000	Antistatic plastic tube				
VS-MBR2045CT-N3	50	1000	Antistatic plastic tube				

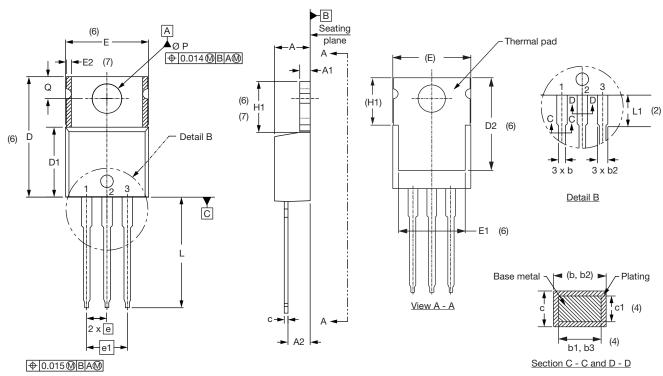
LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95222			
Dout moulcing information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			
SPICE model		www.vishay.com/doc?95295			



### Vishay Semiconductors

### **TO-220AB**

#### **DIMENSIONS** in millimeters and inches



#### Lead assignments

#### <u>Diodes</u>

- 1. Anode/open
- 2. Cathode
- 3. Anode

#### Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIMETERS INCHES		NOTES		
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip

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